(T_j=25 unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	V_D=12V R_L=33	- -	MAX.	5	mA
				10	
V_{GT}		ALL	MAX.	1.3	V
V_{GD}	V_D=V_{DRM} T_j=125 R_L=3.3k	ALL	MIN.	0.2	V
I_L	I_G=1.2I_{GT}	- -	MAX.	10	mA
				20	
I_H	I_T=100mA		MAX.	7	mA
dV/dt	V_D=540V Gate Open T_j=110		MIN.	100	V s
(dV/dt)c	(dI/dt)c=1.8A/ms, T_j=110		MIN.	2.5	
t_{on}	I_G=20mA I_A=200mA I_R=20mA T_j=25		TYP.	2.5	s
t_{off}				25	

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	I_{TM}=5A t_p=380 s	T_j=25	1.55	V
V_{TO}	Threshold voltage	T_j=125	0.92	V
R_D	Dynamic resistance	T_j=125	107	
I_{DRM}	V_D=V_{DRM} V_R=V_{RRM}	T_j=25	5	A
I_{RRM}		T_j=125	0.35	mA

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	18	/W
$R_{th(j-a)}$	junction to ambient (AC)	150	/W

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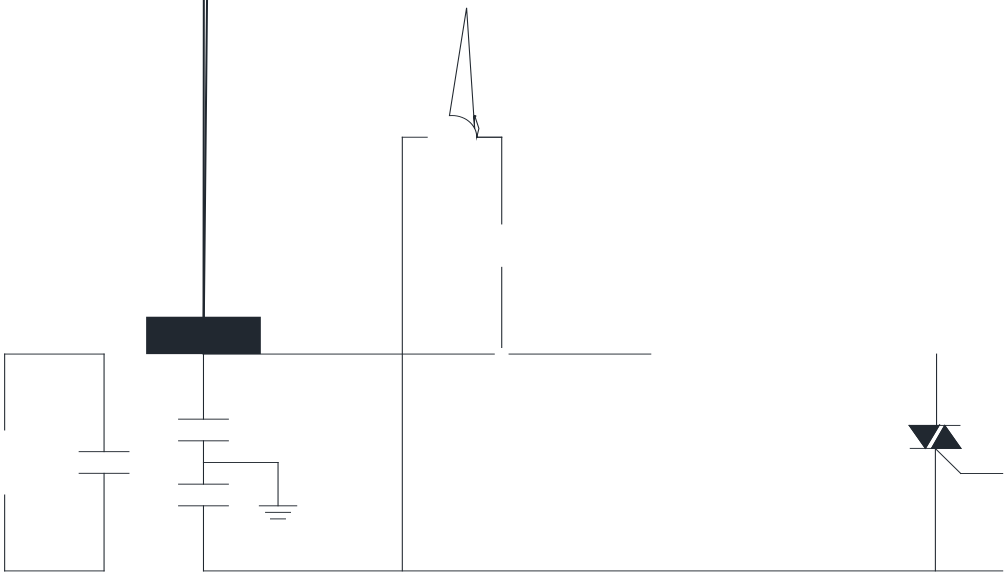
FIG.1: Maximum power dissipation versus RMS on-state current

FIG.2: RMS on-state current versus case temperature

FIG.8 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	1.50		1.80	0.059		0.071
A1					0.002	
B	2.90		3.10	0.114		0.122
B1	0.60		0.80	0.024		0.031
C	0.22		0.32	0.009		0.013
	6.30		6.70	0.248		0.264
	3.30		3.70	0.130		0.146
H	1.50		2.00	0.059		0.079
J	6.70		7.30	0.264		0.287
K						

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
W	-		12.30	-		0.482
E	1.65	1.75	1.85	0.065	0.069	0.073
F	5.45	5.50	5.55	0.215	0.217	0.219
D0		1.55	1.60		0.061	0.063
D1		-	-			
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.95	2.00	2.05	0.077	0.079	0.081
10P0	39.80	40.00	40.20	1.567	1.575	1.583
A0	6.85	6.95	7.05	0.269	0.273	0.276
B0	7.15	7.25	7.35	0.280	0.284	0.288
K0	1.95	2.05	2.15	0.076	0.080	0.084
T	0.20	0.25	0.30	0.008	0.010	0.012

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